ISG56531

5 TO 65 MHz SILICON CATV 31 dB HYBRID AMPLIFIER



FEATURES

FLAT GAIN RESPONSE FROM 5 TO 65 MHz: f=±0.2 dB

• INPUT AND OUTPUT MATCHING TO 75 OHMS: RL => 19 dB

LOW DISTORTION: P1dB = 78 dBmV

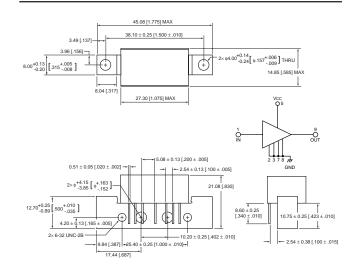
• LOW NOISE: 3.0dB

AUTOMATED SURFACE MOUNT CONSTRUCTION

DESCRIPTION

The ISG56531 is a low noise, low distortion hybrid amplifier specified for use in return path HFC Cable TV applications. The ISG56531 is comprised of 100% surface mount components, including high performance silicon transistors. It features excellent noise, gain, and thermal stability across a wide range of operating conditions and frequencies. The amplifiers are manufactured to ISO9002 standards are very rugged and exhibit excellent unit to unit uniformity.

OUTLINE DIMENSIONS (Units in mm [inches])



ELECTRICAL CHARACTERISTICS (Vcc = 24 V, ± 10% TA = 25°C, 75 Ω System)

PART NUMBER				ISG56531		
SYMBOLS	PARAMETERS	CONDITIONS	UNITS	MIN	TYP	MAX
	Frequency Range	Min (fL) to Max (fH) +5%	MHz	5		65
G	Gain (S ₂₁)	FH = 65 MHz	dB	29.5	30.4	31
GF	Gain Flatness	FL to FH	dB		±0.15	±0.2
RLIN	Input Return Loss (S11)	5-10 MHz	dB	27.0	33.0	
RLin	Input Return Loss (S11)	11-65 MHz	dB	20.0	23.0	
RLout	Output Return Loss	5-10 MHz	dB	25.0	27.0	
RLout	Output Return Loss	11-65 MHz	dB	17.5	19.0	
NF	Noise Figure	5-65 MHz NF	dB		3.0	3.3
	Reverse Isolation (S ₁₂)	RFOUT to RFIN,	dB		34	
		over FH to FL				
СТВ	Composite Triple Beat	See Note 1	dBc			-70
XM	Cross Modulation	See Note 1	dBc			-60
cso	Composite 2nd Order Distortion	See Note 1	dBc		-76	-72
	RFIN to DC and DC to RFOUT	0.3 MHz-5 MHz	dB			-10
P _{1dB}	Output Level at 1 dB Gain Compression	Single tone at				
		any channel frequency	dBmV		78	
Vcc	Supply Voltage		V		24	
Іор	Operating Current at +25°C		mA	170		200
	at -20°C to +100°C					220
Ω	Input & Output Impedance		ohms		75	

Note:

1. Composite Triple Beat, Cross Modulation, 2nd Order Distortion are all measured with 7 channels (T7 through T13) at 50 dBmV/ch output and at 25°C.

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REV. C

ABSOLUTE MAXIMUM RATINGS¹

(Tc = 25 °C unless otherwise noted)

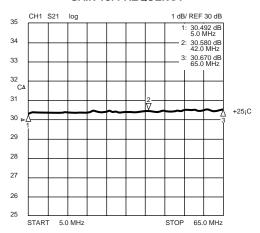
SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	DC Supply	VDC	+28
Vin	RF Input Voltage (Single Tone)	dBmV	+65
Тс	Operating Case Temperature Range	°C	-20 to +100
Тѕтс	Storage Temperature Range	°C	-40 to +100

Note:

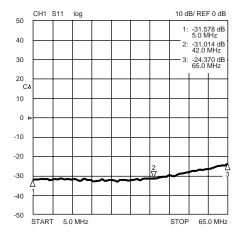
1. Operation in excess of any one of these parameters may result in permanent damage.

TYPICAL PERFORMANCE CURVES (TA = 25°C)

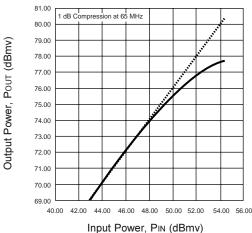
GAIN vs. FREQUENCY



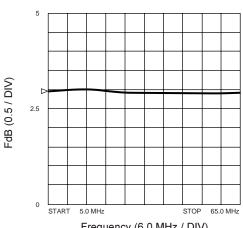
INPUT RETURN LOSS



Power in vs power out @ 65 MHz

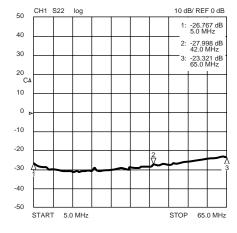


NOISE FIGURE



Frequency (6.0 MHz / DIV)

OUTPUT RETURN LOSS



DATA SUBJECT TO CHANGE WITHOUT NOTICE